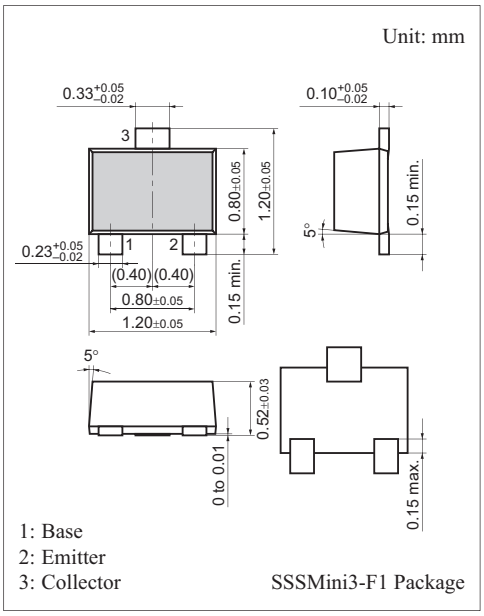
2SC6045

Silicon NPN epitaxial planar type

For UHF band low noise amplification

■ Features

- Low noise figure NF
- High forward transfer gain $|S_{21e}|^2$
- High transition frequency f_T



Marking Symbol: 3M

■ Absolute Maximum Ratings $T_a = 25°C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	15	V
Collector-emitter voltage (Base open)	V_{CEO}	10	V
Emitter-base voltage (Collector open)	V_{EBO}	2	V
Collector current	I_C	80	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	−55 to +125	°C

■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10\ \mu A$, $I_E = 0$	15			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 100\ \mu A$, $I_B = 0$	10			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 10$ V, $I_E = 0$			1	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 2$ V, $I_C = 0$			1	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 8$ V, $I_C = 20$ mA	50	150	300	—
Transition frequency	f_T	$V_{CE} = 8$ V, $I_C = 15$ mA, f = 0.8 GHz	5	6		GHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10$ V, $I_E = 0$, f = 1 MHz		0.7	1.2	pF
Forward transfer gain	$\|S_{21e}\|^2$	$V_{CE} = 8$ V, $I_C = 15$ mA, f = 0.8 GHz	11	14		dB
Maximum unilateral power gain	G_{UM}	$V_{CE} = 8$ V, $I_C = 15$ mA, f = 0.8 GHz		15		dB
Noise figure	NF	$V_{CE} = 8$ V, $I_C = 7$ mA, f = 0.8 GHz		1.3	2.0	dB

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

This product complies with the RoHS Directive (EU 2002/95/EC).

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